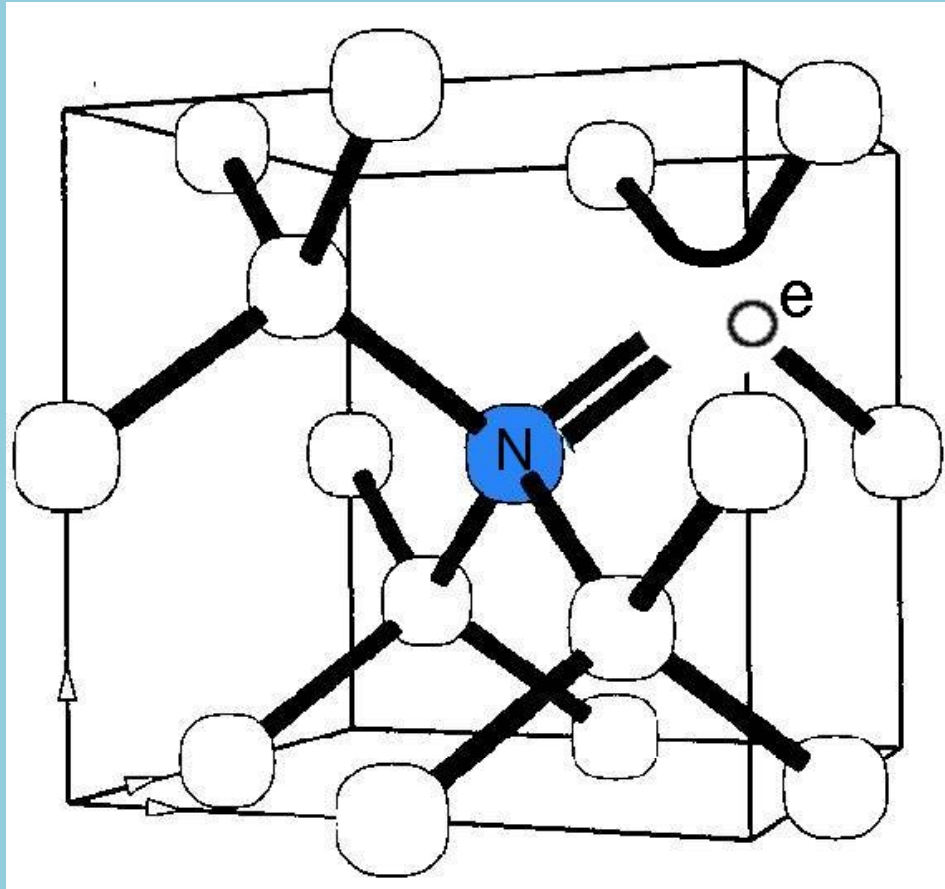


Strain studies in diamond NV centers at UC Berkeley

Lucas Zipp

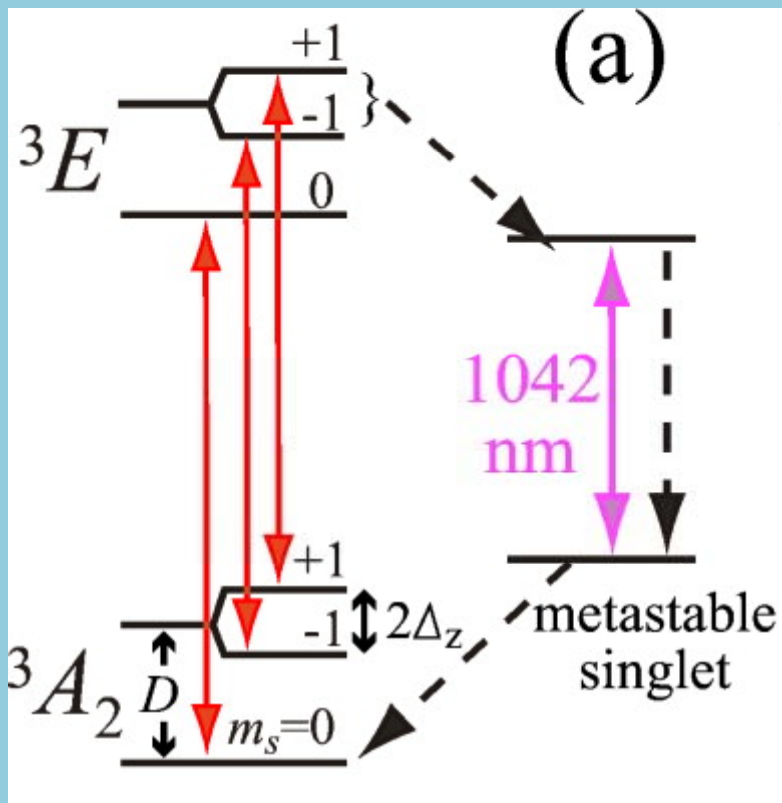
NV⁻ centers



A nitrogen-vacancy center consists of a nitrogen next to a vacancy in the carbon lattice of diamond

Very brief review of NV⁻ centers

Energy Levels



What are they good for?

- Magnetometry- high sensitivity and spatial resolution, competitive with Squid magnetometers
- Quantum Information and Control

Ground state Hamiltonian

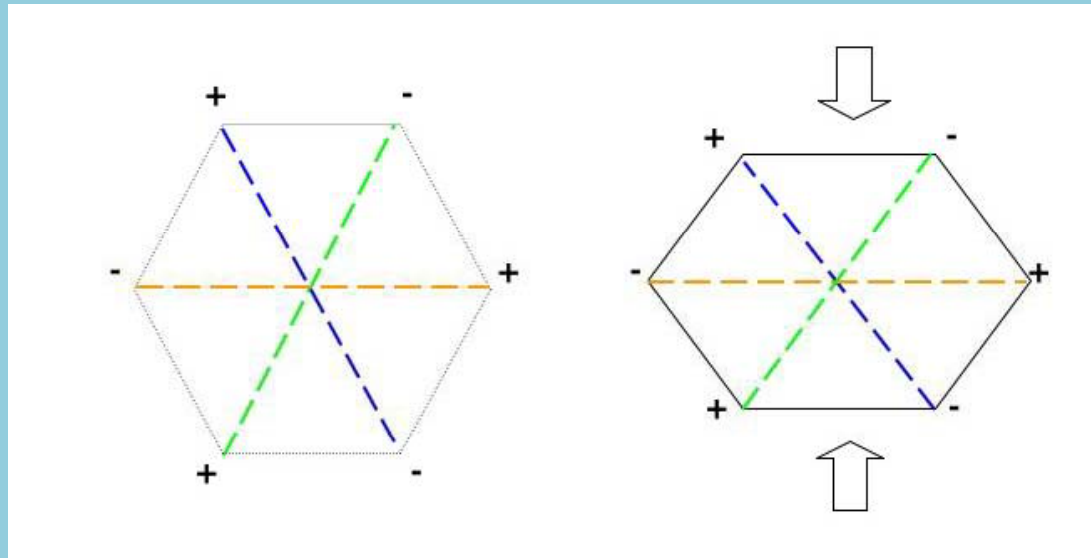
$$H = DS_z^2 + E(S_x^2 - S_y^2) + \mu g \vec{B} \cdot \vec{S}$$

$D \approx 2.87$ GHz and is related to spin-spin interaction

$E \approx$ a few MHz and is related to the strain

Strain and its causes

- Displacement of atomic positions
- Can be applied by mechanical force ie. “squeezing” or electric field. Effect from electric field related to *piezoelectric effect*
- Any deformation of crystal structure leads to strain, even in absence of external force or field.



Piezoelectric effect

My Research: Inherent strain

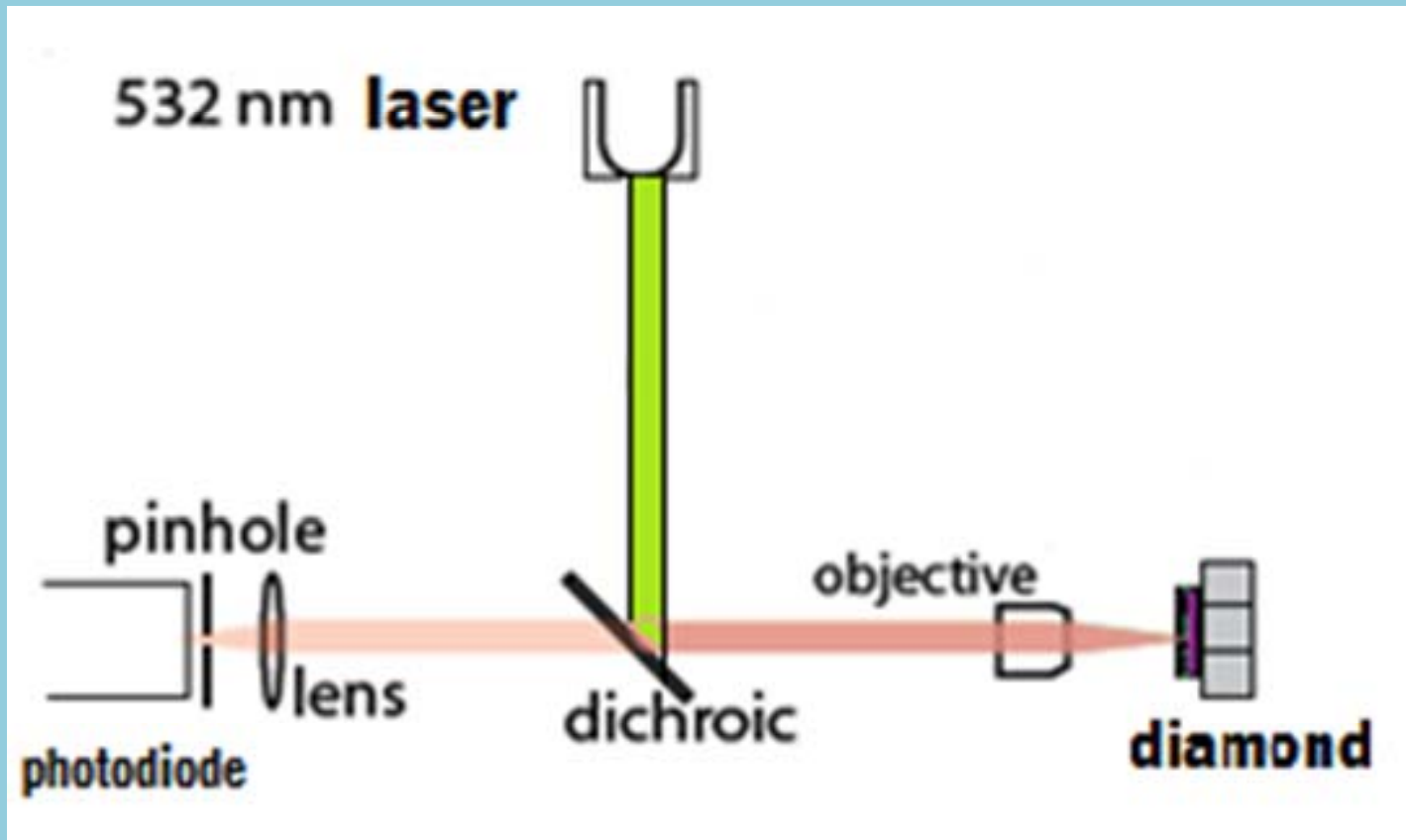
Who cares? (Why stress over strain?)

Answer:

- 1) Destroys linearity of splitting at low B-fields (few Gauss)
- 2) May cause problems for quantum computing

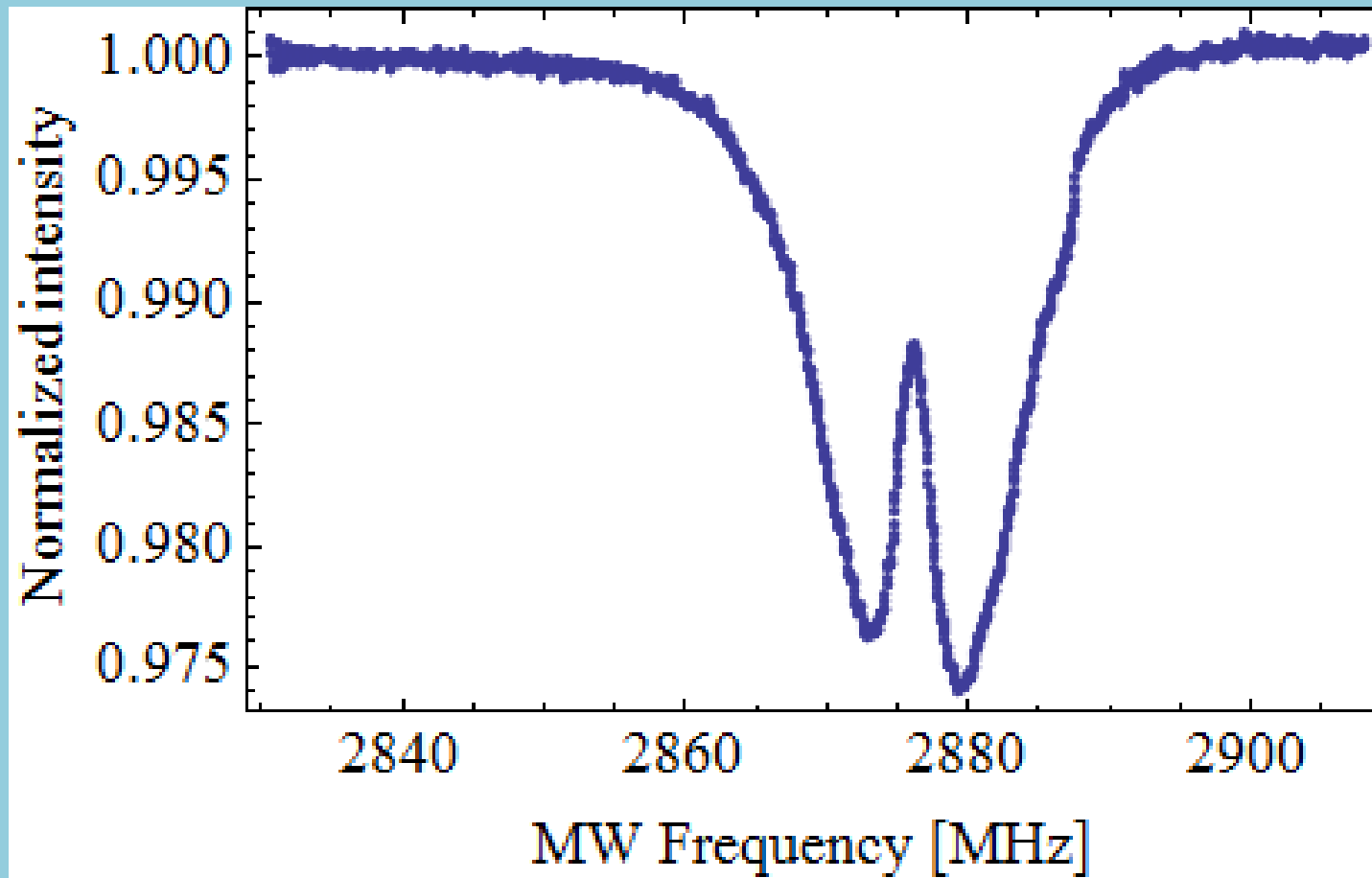
Question is: What are major sources of this deformation?
Defects? Graphitization? Vacancies?

NV⁻ experimental setup

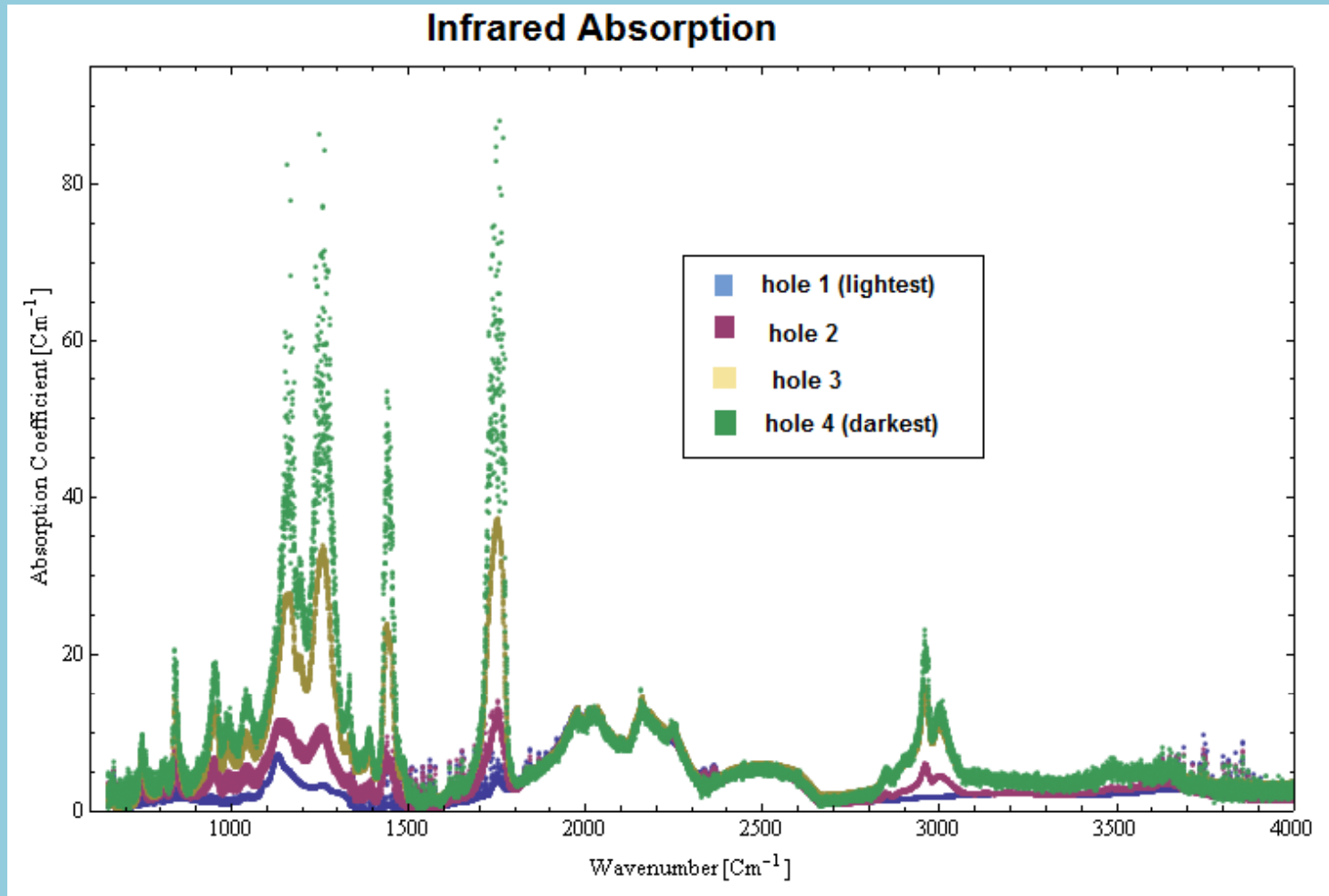


The green laser excites the electrons in the NV centers, creating a red fluorescence, which is then detected by a photodiode.

NV⁻ Resonance Spectrum at zero-field

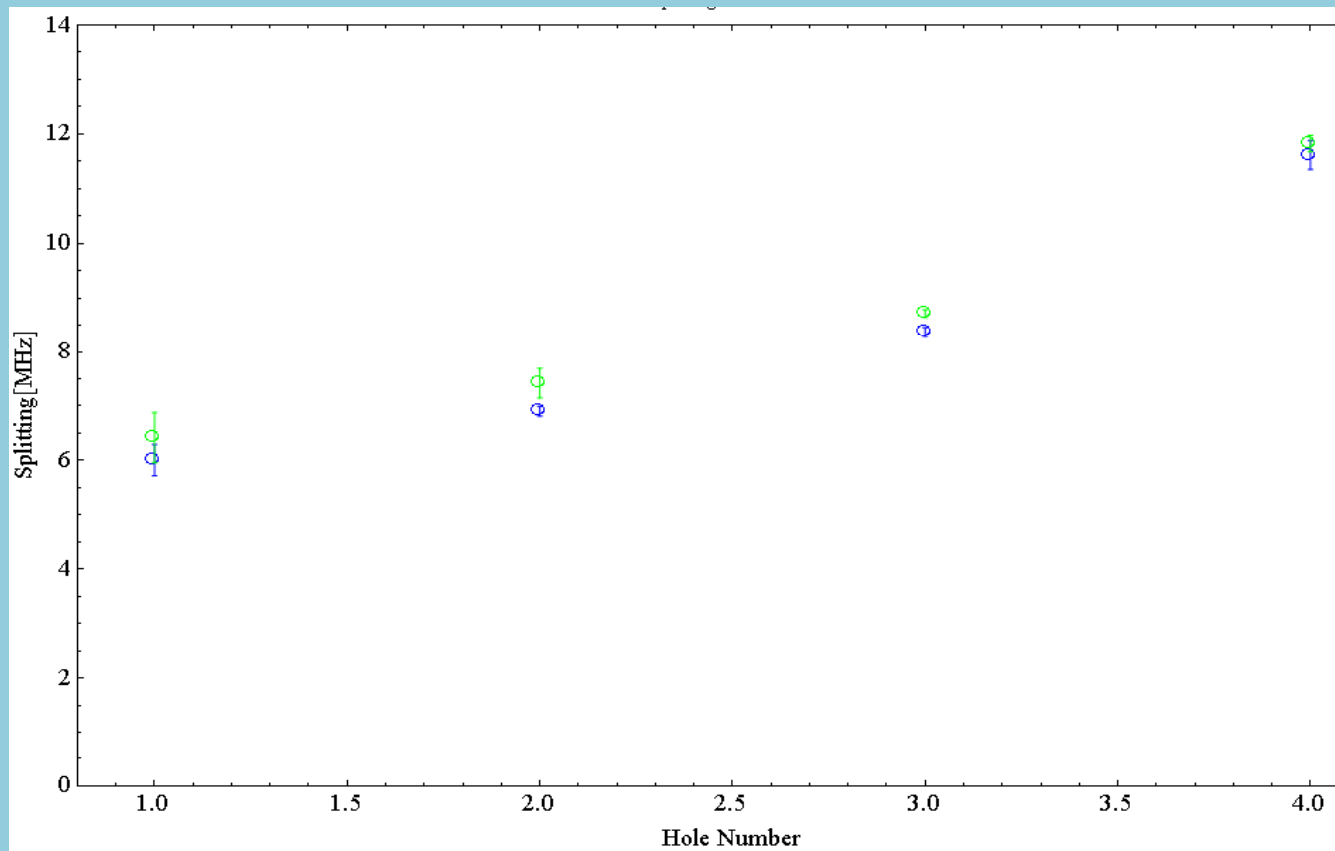


Examined a diamond that contained varying amounts of irradiation damage



Each absorption spectrum is for a different spot on the diamond, It shows increasing amounts of defect creation from irradiation

Tentatively found that zero field splitting increased with increasing irradiation damage



Increasing irradiation damage →

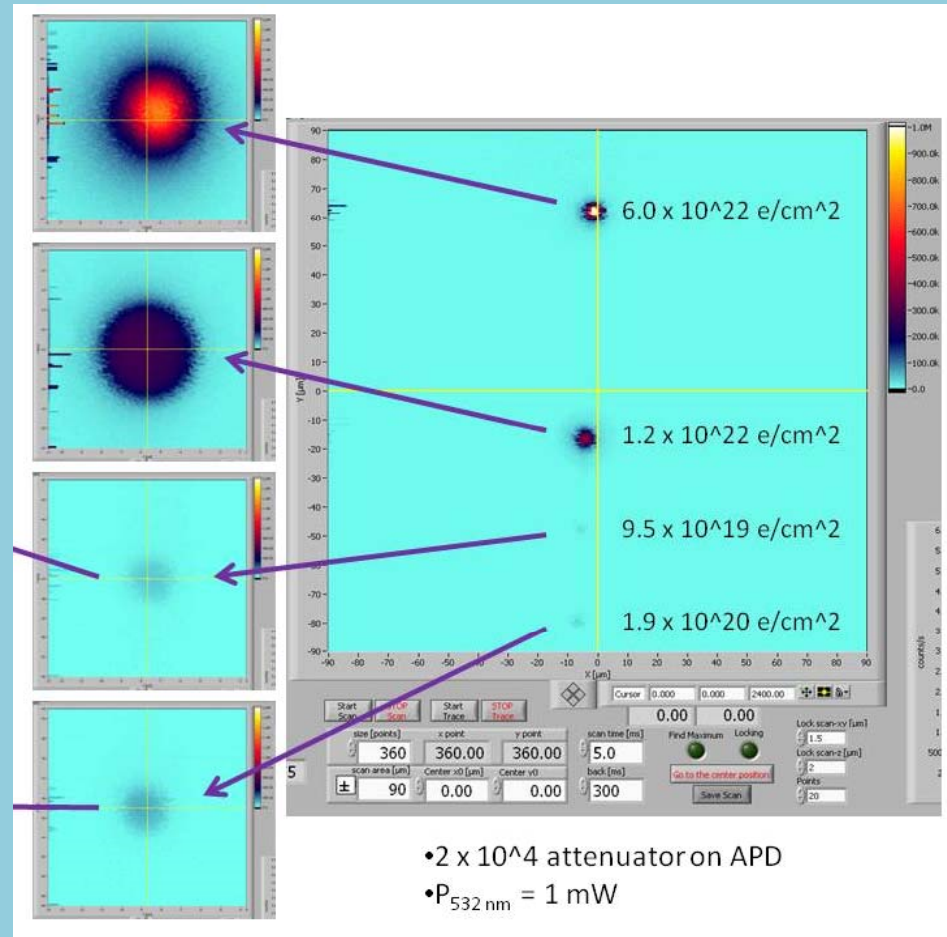
Blue is before 1200 C anneal
Green is after 1200C anneal

Current work- Looking at TEM irradiated spots

Diamond sample was irradiated using a TEM (Transmission Electron Microscope)

200 KeV electrons instead of a few MeV

Preliminary results (as of today) : $E \approx 3$ MHz with < 0.5 MHz variation



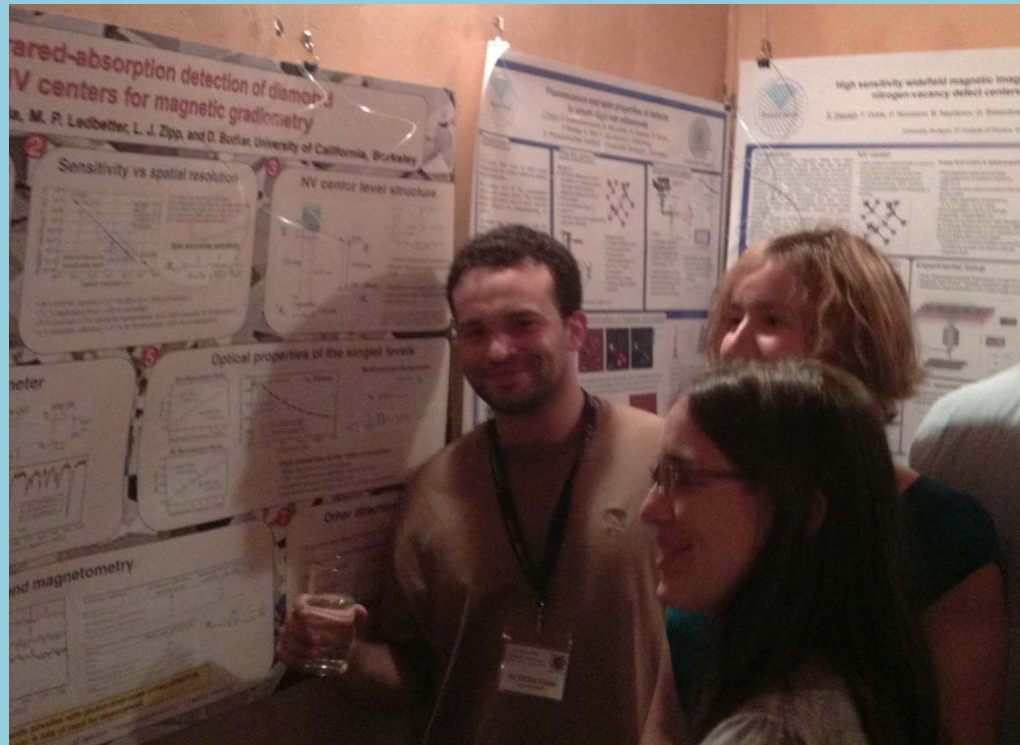
- 2×10^4 attenuator on APD
- $P_{532\text{ nm}} = 1$ mW

Future Research

- Dependence of strain on:
 - Substitutional nitrogen
 - type of diamond (HPHT vs. CVD)
 - energy of electrons

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Recent PhD graduate Victor Acosta